

### **Features**

- Halogen Free. "Green" Device (Note 1)
- · AEC-Q101 Qualified
- · Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

# **Dual PNP Small Signal Transistor**

# Maximum Ratings @ 25°C Unless Otherwise Specified

- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance:625 °C/W Junction to Ambient

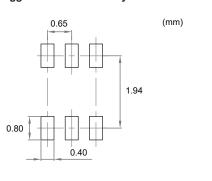
| Parameter                   | Symbol           | Rating | Unit |
|-----------------------------|------------------|--------|------|
| Collector-Base Voltage      | V <sub>CBO</sub> | -60    | V    |
| Collector-Emitter Voltage   | V <sub>CEO</sub> | -60    | V    |
| Emitter-Base Voltage        | V <sub>EBO</sub> | -5     | V    |
| Collector Current           | I <sub>C</sub>   | -600   | mA   |
| Collector Power Dissipation | P <sub>C</sub>   | 200    | mW   |

Note: 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

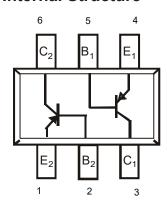
# SOT-363

| DIMENSIONS |         |       |      |      |      |
|------------|---------|-------|------|------|------|
| DIM        | INCHES  |       | MM   |      | NOTE |
| ווועו      | MIN MAX |       | MIN  | MAX  | NOTE |
| Α          | 0.006   | 0.014 | 0.15 | 0.35 |      |
| В          | 0.045   | 0.053 | 1.15 | 1.35 |      |
| С          | 0.079   | 0.096 | 2.00 | 2.45 |      |
| D          | 0.026   |       | 0.65 |      | TYP. |
| G          | 0.047   | 0.055 | 1.20 | 1.40 |      |
| Н          | 0.071   | 0.087 | 1.80 | 2.20 |      |
| J          |         | 0.004 |      | 0.10 |      |
| K          | 0.031   | 0.043 | 0.80 | 1.10 |      |
| L          | 0.010   | 0.018 | 0.26 | 0.46 |      |
| М          | 0.003   | 0.006 | 0.08 | 0.15 |      |

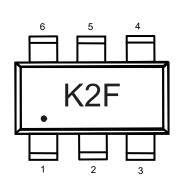
#### Suggested Solder Pad Layout



# **Internal Structure**



# Marking: K2F





# Electrical Characteristics @ 25°C Unless Otherwise Specified

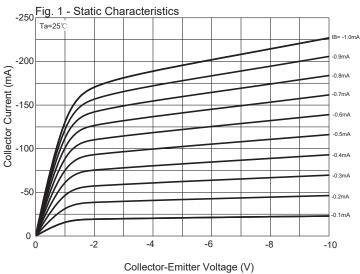
| Parameter                            | Symbol               | Min | Тур | Max  | Units | Conditions   |  |
|--------------------------------------|----------------------|-----|-----|------|-------|--|--|
| Collector-Base Breakdown Voltage     | V <sub>(BR)CBO</sub> | -60 |     |      | V     | I <sub>C</sub> =-10μA, I <sub>E</sub> =0   |  |
| Collector-Emitter Breakdown Voltage  | V <sub>(BR)CEO</sub> | -60 |     |      | V     | I <sub>C</sub> =-10mA, I <sub>B</sub> =0   |  |
| Emitter-Base Breakdown Voltage       | V <sub>(BR)EBO</sub> | -5  |     |      | V     | I <sub>E</sub> =-10μA, I <sub>C</sub> =0   |  |
| Collector-Base Cutoff Current        | I <sub>CBO</sub>     |     |     | -20  | nA    | V <sub>CB</sub> =-50V, I <sub>E</sub> =0   |  |
| Collecto Cutoff Current              | I <sub>CEX</sub>     |     |     | -50  | nA    | V <sub>CE</sub> =-30V, V <sub>EB(off)</sub> =-0.5V                                   |  |
| Emitter-Base Cutoff Current          | I <sub>EBO</sub>     |     |     | -20  | nA    | $V_{EB}$ =-5V, $I_C$ =0  |  |
| DC Current Gain <sup>(Note2)</sup>   | h <sub>FE(1)</sub>   | 75  |     |      |       | V <sub>CE</sub> =-10V, I <sub>C</sub> =-0.1mA  |  |
|                                      | h <sub>FE(2)</sub>   | 100 |     |      |       | V <sub>CE</sub> =-10V, I <sub>C</sub> =-1mA  |  |
|                                      | h <sub>FE(3)</sub>   | 100 |     |      |       | V <sub>CE</sub> =-10V, I <sub>C</sub> =-10mA   |  |
|                                      | h <sub>FE(4)</sub>   | 100 |     | 300  |       | V <sub>CE</sub> =-10V, I <sub>C</sub> =-150mA  |  |
|                                      | h <sub>FE(5)</sub>   | 50  |     |      |       | V <sub>CE</sub> =-10V, I <sub>C</sub> =-500mA  |  |
| Collector-Emitter Saturation Voltage | V <sub>CE(sat)</sub> |     |     | -0.4 | V     | I <sub>C</sub> =-150mA, I <sub>B</sub> =-15mA  |  |
|                                      |                      |     |     | -1.6 | V     | I <sub>C</sub> =-500mA, I <sub>B</sub> =-50mA  |  |
| Base-Emitter Saturation Voltage      | V <sub>BE(sat)</sub> |     |     | -1.3 | V     | I <sub>C</sub> =-150mA, I <sub>B</sub> =-15mA  |  |
|                                      |                      |     |     | -2.6 | V     | I <sub>C</sub> =-500mA, I <sub>B</sub> =-50mA  |  |
| Transition Frequency                 | f <sub>T</sub>       | 200 |     |      | MHz   | V <sub>CE</sub> =-20V, I <sub>C</sub> =-50mA, f=100MHz                               |  |
| Output Capacitance                   | C <sub>cbo</sub>     |     |     | 8    | pF    | V <sub>CB</sub> =-10V, I <sub>E</sub> =0, f=1MHz,                                    |  |
| Input Capacitance                    | C <sub>ibo</sub>     |     |     | 30   | pF    | $V_{EB}$ =-2V, $I_C$ =0, f=1MHz,   |  |
| Delay Time                           | t <sub>d</sub>       |     |     | 10   | ns    | V <sub>CC</sub> =-30V, I <sub>C</sub> =-150mA I <sub>B1</sub> =-15mA                 |  |
| Rise Time                            | t <sub>r</sub>       |     |     | 40   | ns    |  |  |
| Storage Time                         | t <sub>s</sub>       |     |     | 225  | ns    | V <sub>CC</sub> =-6V, I <sub>C</sub> =-150mA I <sub>B1</sub> =I <sub>B2</sub> =-15mA |  |
| Fall Time                            | t <sub>f</sub>       |     |     | 60   | ns    |  |  |

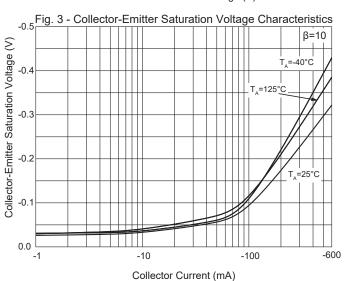
Note: 2.Pulse Width ≤ 300µs, Duty Cycle≤2.0%

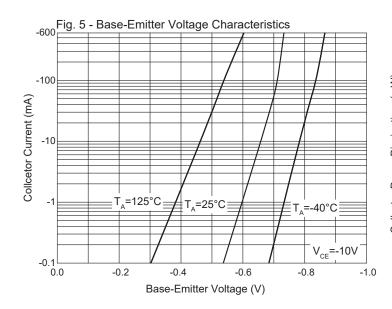
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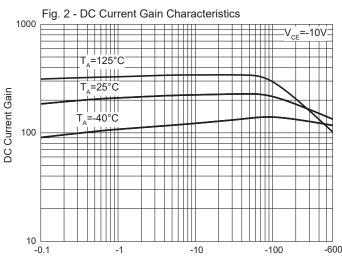


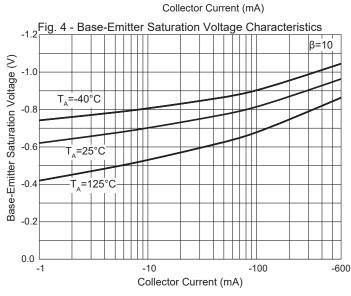
## **Curve Characteristics**

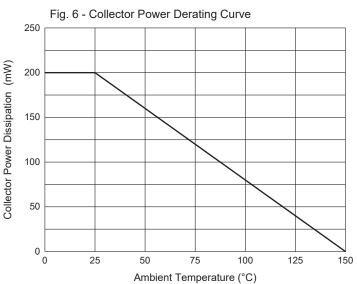














# **Ordering Information**

| Device          | Packing               |  |  |
|-----------------|-----------------------|--|--|
| MMDT2907AHE3-TP | Tape&Reel: 3Kpcs/Reel |  |  |

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